NSN 5961-01-511-4261

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-511-4261 **Inclosure Material:** Glass **Overall Length:** 0.300 inches **Terminal Length:** 0.975 inches **Overall Diameter:** 0.145 inches **Function For Which Designed:** Transient suppressor **Mounting Method: Terminal Terminal Circle Diameter:** 0.040 inches **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 27.0 breakdown voltage, dc **Current Rating Per Characteristic:** 12.00 amperes source cutoff current universal **Power Rating Per Characteristic:** 500.0 watts small-signal output power, common-base pascal **Maximum Operating Tempurature Per Measurement Point:** 175.0 degrees celsius ambient air **Terminal Type And Quantity:** 2 uninsulated wire lead Shelf Life: N/a **Unit Of Measure: Demilitarization:** No

Fiig: A110a0